



### SV0806H431G0A

### Description

The SV0806H431G0A is based on Multilayer fabrication technology. These components are designed to suppress a variety of transient events, including those specified in IEC 61000-4-2 or other standards used for Electromagnetic Compliance (EMC). The SV0806H431G0A is typically applied to protect integrated circuits and other components at the circuit board level. It can operate over a wider temperature range than zener diodes.



#### Features

- Rectangle, sizes serialization for hybrid integrated circuit or printed circuit surface mount components
- There are many side electrode lead-out material, particularly suitable for surface mount technology for solderability and resistance to soldering heat of the stringent requirements
- ♦ Fast response (<1ns)</p>
- Low leakage current, low clamping voltage
- Suitable for reflow, wave soldering and hot air hand soldering

#### Applications

- Application for Mother Board, Notebook, Cellular Phone, PDA, handheld device, DSC, DV, Scanner, and Set- Top Box...etc.
- Suitable for Push-Button, Power Line and Low Frequency single line over-voltage protect.





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### Electrical Characteristics (25±5℃)

Symbol	Minimum	Typical	Maximum	Units
V <sub>RMS</sub>	—	_	275	V
V <sub>DC</sub>	—	—	350	V
Vv	387	_	473	V
Vc	—	_	710	V
IP	_	_	50	А

 $V_{RMS}$  - Maximum AC operating voltage the varistor can maintain and not exceed 30µA leakage current.

 $V_{DC}$  - Maximum DC operating voltage the varistor can maintain and not exceed 30µA leakage current.

- $V_V\,$  Voltage across the device measure at 1mA DC current. Equivalent to  $V_{BR}$  "breakdown voltage".
- $Vc\,$  Maximum peak current across the varistor with 8/20  $\mu s$  waveform and 1A pulse current.
- IP Maximum peak current which may be applied with 8/20µs waveform without device failure.





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### Shape & Dimensions and Parts & Components

Shape & Dimensions: See Fig.1 and Table 1. Parts &Components: See Fig.2 and Table 2.



Table 1					
Туре	L (mm)	W (mm)	T (mm)	a (mm)	
0806	2.00±0.25	1.60±0.30	1.90 Max.	0.40±0.20	

Fig.2



Table 2					
Part	1	2	3		
Component	ZnO Semiconductor Ceramics for Chip Varistor	Internal Electrode (Ag or Ag-Pd)	Terminal Electrode (Ag/Ni/Sn three layers)		





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#### **Soldering Recommendation**

#### **Recommended Soldering Profile**

- ◆ Pb Free Solder Paste: Sn/Ag/Cu (96.5/3.0/0.5).
- Max time at max temp: 10sec.
- Allowed Reflow time: 2x Max.



### **Packaging Quantity**

Туре	Таре	Quantity (pcs/reel)
SV0806H431G0A	Embossed Tape	2000

#### **Notes & Warnings**

- ◆ Storage temperature in original packaging: -10~+40°C.
- ♦ Relative Humidity: ≤70%RH.
- Keep away from corrosive atmosphere and sunlight.
- Period of Storage: 12 Months.